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Processor-based built-in self-test for embedded DRAM

Dreibelbis, J. Barth, J. Kalter, H. Kho, R.

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Abstract:

A built-in self-test engine and test methodology have been developed for testing a fa of high-bandwidth, high-density DRAM macros. The DRAM macros range in size from $256 \times 16 \times 128$ to 2 K $\times 16 \times 256$ (Word \times Bit \times Data) and are targeted for embedded applications in application-specific integrated circuit designs. The processor-based te engine, with two separate instruction storage memories, combines with flexible addre data, and clock generators to provide DRAM high-performance ac testing using a minimum of dedicated test pins. Test results are compressed through on-macro, two dimensional, redundancy allocation logic to provide direct programming information 1 the fuser via a serial scan port. The design is intended for reuse on future DRAMgeneration subarrays and can be adapted to any number of address or data-pin configurations

Index Terms:

application specific integrated circuits built-in self test integrated circuit testing memory architecture random-access storage redundancy DRAM-generation subarrays applicationspecific integrated circuit designs built-in self-test engine clock generators data-pin configurations dedicated test pins direct programming information embedded DRAM high-d DRAM macros instruction storage memories processor-based built-in self-test redundancy allocation logic serial scan port test methodology

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